NSN 5962-01-388-4184

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating: 1.5 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Case Outline Source And Designator:** D-9 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 15.00 nanoseconds delay Memory Device Type: Pal **Nuclear Hardness Critical Feature:** Hardened **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a Unit Of Measure: --**Demilitarization:** Yes - demil/mli Fiig: A458a0